
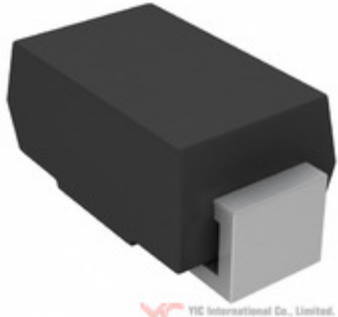
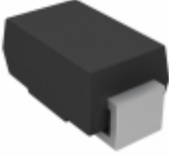
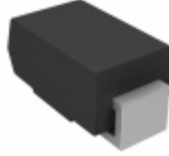
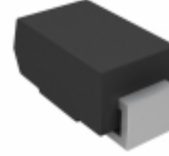
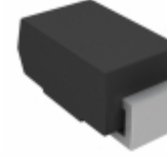

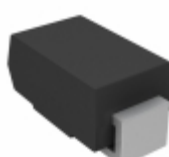

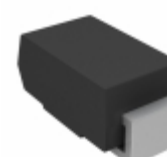
	<p><b>S1GHE3_A/H</b></p>
	<p><b>Hersteller-Teilenummer:</b> S1GHE3_A/H</p> <p><b>Hersteller / Marke:</b> Vishay / Semiconductor - Diodes Division</p> <p><b>Teil der Beschreibung:</b> DIODE GEN PURP 400V 1A DO214AC</p> <p><b>Datenblätter:</b>  <a href="#">S1GHE3_A/H.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 3689 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	S1GHE3_A/H
Hersteller	Vishay / Semiconductor - Diodes Division
Beschreibung	DIODE GEN PURP 400V 1A DO214AC
Kategorie	Diskrete Halbleiterprodukte > Dioden-Gleichrichter-
Teilstatus	3689 pcs Stock
Serie	-
Befestigungsart	Surface Mount
Verpackung / Gehäuse	DO-214AC, SMA
Supplier Device-Gehäuse	DO-214AC (SMA)
Diodentyp	Standard
Strom - Richt (Io)	1A
Spannung - Forward (Vf) (Max) @ If	1.1V @ 1A
Strom - Sperrleckstrom @ Vr	1µA @ 400V
Spannung - Sperr (Vr) (max)	400V
Geschwindigkeit	Standard Recovery >500ns, > 200mA (Io)
Rückwärts-Erholzeit (Trr)	1.8µs
Betriebstemperatur - Anschluss	-55°C ~ 150°C
Kapazität @ Vr, F	12pF @ 4V, 1MHz
Verpackung	Tape & Reel (TR)

S1GHE3\_A/H ist neu im Original, Suche S1GHE3\_A/H Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie S1GHE3\_A/H Vishay / Semiconductor - Diodes Division mit Garantie und Vertrauen. Anfrage S1GHE3\_A/H: Info@Y-IC.com

Sie können auch interessiert sein:

 <p><b>S1GHE3/61T</b> Vishay / Semiconductor - Diodes Division DIODE GEN PURP 400V 1A DO214AC</p>	 <p><b>S1GHE3_A/H</b> Electro-Films (EFI) / Vishay DIODE GEN PURP 400V 1A DO214AC</p>	 <p><b>S1GHE3/61T</b> Electro-Films (EFI) / Vishay DIODE GEN PURP 400V 1A DO214AC</p>	 <p><b>S1GHE3_A/I</b> Electro-Films (EFI) / Vishay DIODE GEN PURP 400V 1A DO214AC</p>
 <p><b>S1GHE3</b> VISHAY S1GHE3 VISHAY</p>	 <p><b>S1GHE3/5AT</b> Vishay / Semiconductor - Diodes Division DIODE GEN PURP 400V 1A DO214AC</p>	 <p><b>S1GHM3/61T</b> Electro-Films (EFI) / Vishay DIODE GEN PURP 400V 1A DO214AC</p>	 <p><b>S1GHE3/5AT</b> Electro-Films (EFI) / Vishay DIODE GEN PURP 400V 1A DO214AC</p>

heiße Teile

Mehr

- |                   |                      |                  |                 |                  |
|-------------------|----------------------|------------------|-----------------|------------------|
| ⚙ AT-41411-TR1G   | ➔ C2012CH1H822J060AA | ➔ FET13066       | D GCIXP1200GC   | ➔ IMP1117ADX/T   |
| ⚡ IRFZ44STRL      | ⚙ IRKH56/08          | D LS03-05B09SC   | ➔ LX7169CLD-TE  | ➔ MAZS3000HL     |
| ⚙ NFW31SP506X1E4L | ⚡ P0465CTF           | ⚙ RSX201VA-30TR  | ➔ S1G-003/5AT   | ➔ S1G-003HE3/5AT |
| D S1G-008/11      | ⚙ S1G-012/5A         | ⚡ S1G-012/5AT    | ⚙ S1G-13-93-F   | ➔ S1G-13-F       |
| ➔ S1G-13-F-89     | ➔ S1G-13-G-89        | ⚙ S1G-61HE3J/61T | ⚡ S1G-6428E3/11 | ➔ S1G-6601       |
| ➔ S1G-6904E3/61   | ➔ S1G-6904E3/61T     | D S1G-6904LF/11T | ⚙ S1G-E3/5AT    | ⚡ S1G-E3/5AT     |
| ⚙ S1G-E3/61T      | D S1G-E3/61T         | ➔ S1G-GS/61T     | ➔ S1G-M3/61T    | ➔ S1G-M3/61T     |
| ⚡ S1G-TR13        | ⚙ S1GA-E3/61T        | ➔ S1GA-E3/61T    | ➔ S1GB-13-F     | ➔ S1GHE3/5AT     |
| ⚙ S1GHE3/5AT      | ⚡ S1GHE3/61T         | ⚙ S1GHE3/61T     | D S1GHE3_A/H    | ➔ S1GT-04LC-F    |
| ➔ S1G_R1_10001    | ⚙ SMAJ30CA           | ⚡ SP3074EMN      | ⚙ SY100EL29VZG  | ➔ VKA50MS24      |

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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